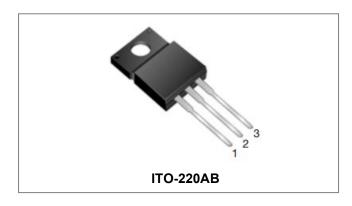






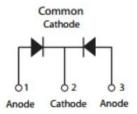
### SDURF2060CT ULTRAFAST RECTIFIER



### **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

# **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- · High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	100	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@10A, Pulse, T <sub>J</sub> = 25°C	1.76	2.2	V
	V <sub>F2</sub>	@10A, Pulse, T <sub>J</sub> = 125°C	-	2.0	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.02	10	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ , $T_J = 125^{\circ}C$	-	500	μA
Reverse Recovery Time(Per Leg)	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	42	50	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	Rejc	DC operation	5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

### **Ratings and Characteristics Curves**

Figure 1. Typical Forward Voltage Drop vs. Forward Current

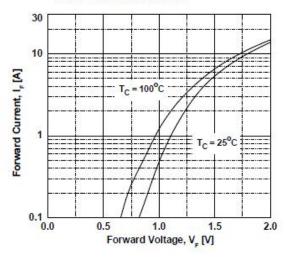


Figure 2. Typical Reverse Current vs. Reverse Voltage

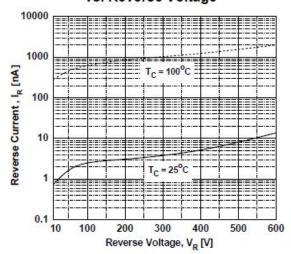


Figure 3. Typical Junction Capacitance

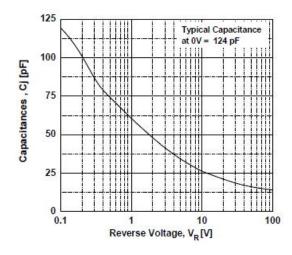
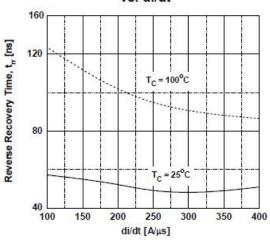


Figure 4. Typical Reverse Recovery Time vs. di/dt



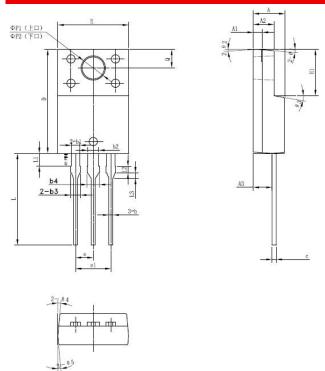
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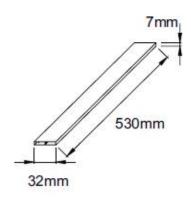


#### **Mechanical Dimensions ITO-220AB**

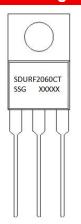


CVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦΡ1( ├ □ )	3.30	3.50	3.70	
<b>ΦP2</b> (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

#### **Tube Specification**



#### **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type
F = Package type
20 = Forward Current (20A)
60 = Reverse Voltage (600V)
CT = Configuration
SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

#### **Ordering Information**

Device	Package	Shipping
SDURF2060CT	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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